



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
	$16m\Omega @ V_{GS} = -4.5V$	-9.1A
	21.5mΩ @ V _{GS} = -2.5V	-7.9A
-12V	26mΩ @ V _{GS} = -1.8V	-7.0A
	32mΩ @ V _{GS} = -1.5V	-6.3A

Description

This MOSFET is designed specifically for use in battery management applications.

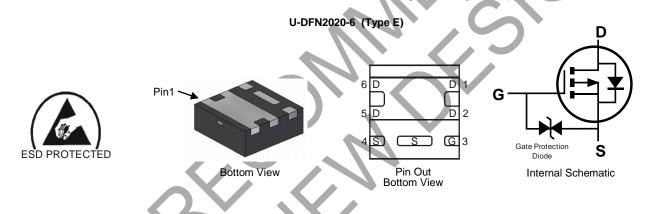
12V P-CHANNEL ENHANCEMENT MODE MOSFET

Features

- 0.6mm Profile Ideal For Low Profile Applications •
- PCB Footprint of 4mm²
- Low Gate Threshold Voltage
- Fast Switching Speed
- ESD Protected to 3KV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (DMP1022UFDEQ)

Mechanical Data

- Case: U-DFN2020-6 (Type E)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4)
- Weight: 0.0065 grams (Approximate)



Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Quantity Per Reel
DMP1022UFDE-7	P4	7	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and 1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:

₽4 ⋛ •	P4 = Product YM = Date C Y = Year (ex: M = Month (e
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t Type Marking Code

- ode Marking
- : E = 2017)
- ex: 9 = September)

Date Code Key												
Year	2011	~	2015	2016	5 20 1	7 2	018	2019	2020	2021	2022	2023
Code	Y	~	С	D	E		F	G	Н	I	J	K
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Au	g Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage		V _{DSS}	-12	V	
Gate-Source Voltage			V _{GSS}	±8	V
	Steady State	T _A = +25°C T _A = +70°C	ID	-9.1 -7.2	А
Continuous Drain Current (Note 6) $V_{GS} = -4.5V$	t<5s $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$		ID	-11.2 -9.0	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		IDM	-90	А	
Continuous Source-Drain Diode Current	$T_{A} = +25^{\circ}C$ $T_{C} = +25^{\circ}C$	I _S	-2.5 -7.1	А	
Pulsed Source-Drain Diode Current (10µs Pulse, Du	I _{SM}	-50	А		

Thermal Characteristics

	Symbol	Value	Unit
T _A = +25°C T _A = +70°C	PD	0.66	W
Steady State t<5s	Reja	189 123	°C/W
$T_{A} = +25^{\circ}C$ $T_{A} = +70^{\circ}C$	PD	2.03 1.3	W
Steady State t<5s	R _{0JA}	61 40	°C/W
Steady State	R _{ejc}	9.3	1
	T _J , T _{STG}	-55 to +150	°C
	$T_A = +70^{\circ}C$ Steady State $t<5s$ $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ Steady State $t<5s$	$\begin{tabular}{ c c c c c c } \hline T_A = +25^\circ C & P_D \\ \hline T_A = +70^\circ C & P_D \\ \hline Steady State & \\ \hline t < 5s & \\ \hline T_A = +25^\circ C & P_D \\ \hline T_A = +70^\circ C & P_D \\ \hline Steady State & \\ \hline t < 5s & \\ \hline Steady State & \\ \hline R_{\theta JA} \\ \hline \end{tabular}$	$ \begin{array}{c c c c c c c c c c c c c c c c c c c $

 Notes:
 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1-inch square copper plate.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	.		- 71-			
Drain-Source Breakdown Voltage	BV _{DSS}	-12	_	_	V	V _{GS} = 0V, I _D = -250µA
Zero Gate Voltage Drain Current (T _J = +25°C)	I _{DSS}	_	—	-200	nA	$V_{DS} = -12V, V_{GS} = 0V$
Zero Gate Voltage Drain Current ($T_J = +55^{\circ}C$) (Note 8)	IDSS		—	-2	μA	$V_{DS} = -12V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	-	—	±2	μA	$V_{GS} = \pm 5V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	-0.35	—	-0.8	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
V _{GS(TH)} Temperature Coefficient	$\Delta V_{GS(TH)} / \Delta T_J$	_	2.5	_	mV/°C	I _D = -250μA
On-State Drain Current	I _{D(ON)}	-10	_			V _{GS} = -4.5V, V _{DS} < -5A
			12	16		V _{GS} = -4.5V, I _D = -8.2A
			15	21.5		V _{GS} = -2.5V, I _D = -7.2A
Static Drain-Source On-Resistance	R _{DS(ON)}	_	20	26	mΩ	V _{GS} = -1.8V, I _D = -6.6A
			23	32		$V_{GS} = -1.5V, I_D = -1A$
			80	160		V _{GS} = -1.2V, I _D = -1A
Forward Transfer Admittance	Y _{fs}	_	12		S	$V_{DS} = -4V, I_{D} = -8.2A$
Diode Forward Voltage	V _{SD}	_	-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -8A$
DYNAMIC CHARACTERISTICS (Note 8)					Ψ	
nput Capacitance	C _{iss}	—	2,953	—		
Output Capacitance	Coss	-	756	—	pF	$V_{DS} = -4V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}		678			
Gate Resistance	R _q	+	8.6	18	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Qa	-	28.4	42.6		V _{GS} = -5V, V _{DS} = -4V, I _D = -10A
Total Gate Charge	Q _a		25.3	38		÷
Gate-Source Charge	Q _{as}		2.3		nC	$V_{GS} = -4.5V, V_{DS} = -4V,$
Gate-Drain Charge	Q _{ad}	<u> </u>	7.2	—		I _D = -10A
Turn-On Delay Time	t _{D(ON)}	—	20	30		
Turn-On Rise Time	tR	_	28	42		$V_{DS} = -4V, V_{GS} = -4.5V,$
Turn-Off Delay Time	t _{D(OFF)}	-	117	176	ns	$R_{G} = 1\Omega, R_{L} = 0.4\Omega, I_{D} = -9.8A$
Turn-Off Fall Time	tF	-	93	139		
BODY DIODE CHARACTERISTICS						
Diode Forward Voltage	V _{SD}	Ŧ	-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -9.8A$
Continuous Source-Drain Diode Current (Note 6)			—	-2.5		T _A = +25°C
Johannuous Source-Drain Diode Current (Note 6)	ls		—	-7.1	А	$T_{C} = +25^{\circ}C$
Pulse Diode Forward Current (Note 8)	I _{SM}	_	—	-50		
Body Diode Reverse Recovery Time (Note 8)	t _{RR}		28	56		
Reverse Recovery Fall Time	tA		10		ns	
		_	18	_	1	I _S = -9.8A, dl/dt = 100A/µs
Reverse Recovery Rise Time	tB		10			

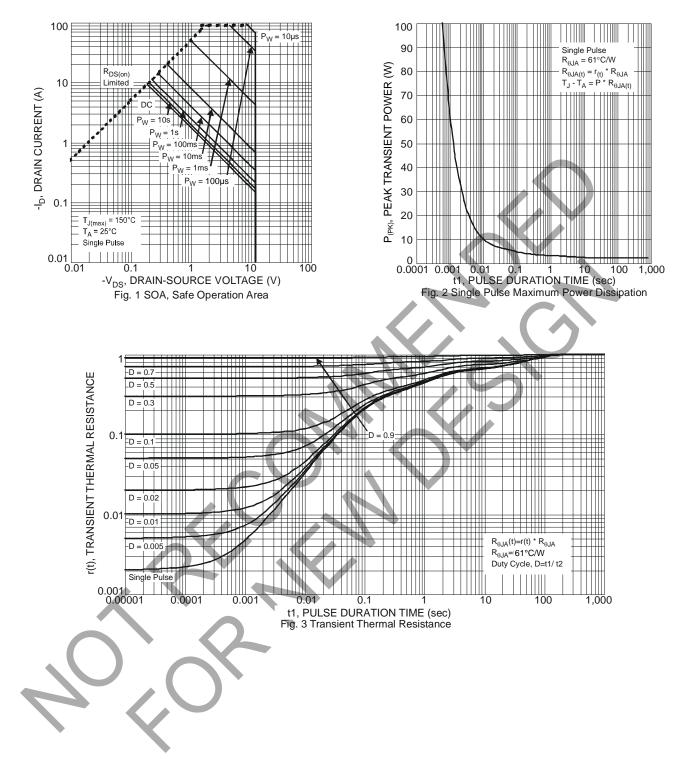
Notes:

Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing.



NOT RECOMMENDED FOR NEW DESIGN USE <u>DMP1005UFDF</u>

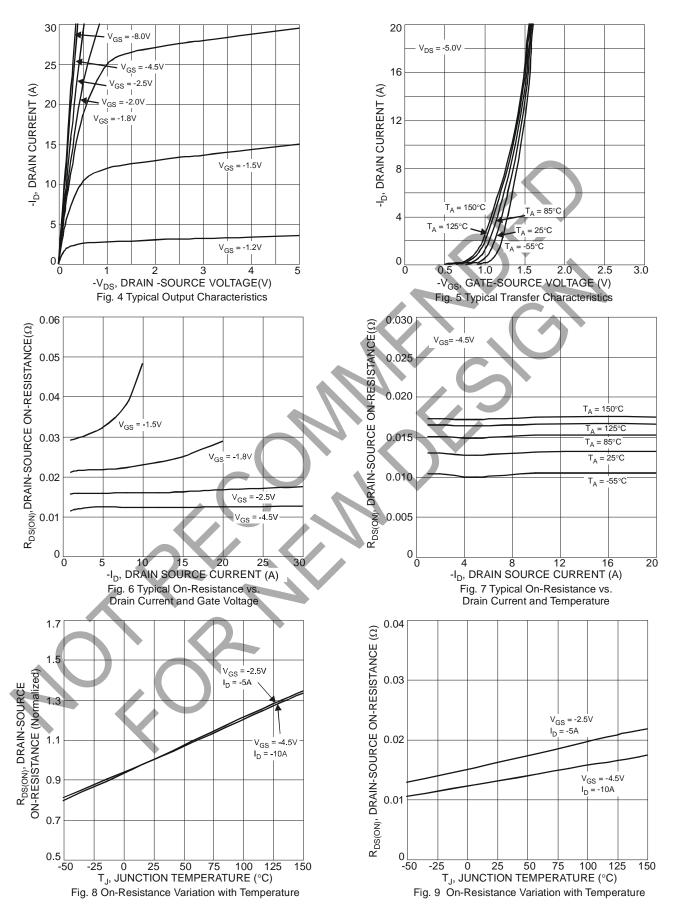
DMP1022UFDE





NOT RECOMMENDED FOR NEW DESIGN USE <u>DMP1005UFDF</u>

DMP1022UFDE

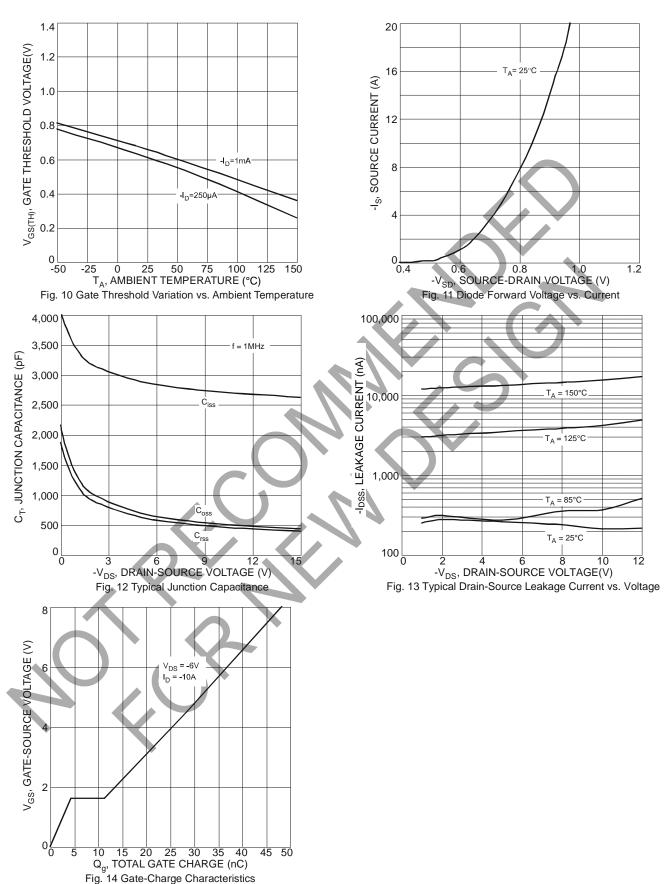


DMP1022UFDE Datasheet number: DS35477 Rev. 12 - 3 Downloaded from Arrow.com.



NOT RECOMMENDED FOR NEW DESIGN USE <u>DMP1005UFDF</u>

DMP1022UFDE



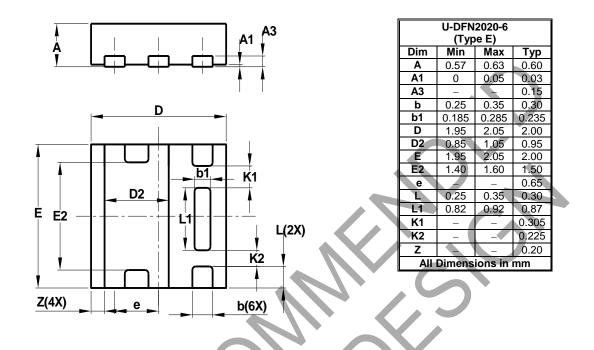
DMP1022UFDE Datasheet number: DS35477 Rev. 12 - 3 Downloaded from Arrow.com.



Package Outline Dimensions

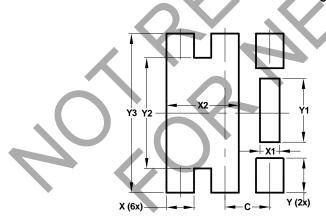
Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type E)



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



U-DFN2020-6 (Type E)

Dimensions	Value (in mm)
С	0.650
Х	0.400
X1	0.285
X2	1.050
Y	0.500
Y1	0.920
Y2	1.600
Y3	2.300



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